
PATENT OWNER'S EXHIBIT 2004



US006806652B1

(12) **United States Patent**
Chistyakov

(10) **Patent No.:** US 6,806,652 B1
(45) **Date of Patent:** *Oct. 19, 2004

(54) **HIGH-DENSITY PLASMA SOURCE USING EXCITED ATOMS**

FOREIGN PATENT DOCUMENTS

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WO WO 98/40532 9/1998
WO WO 01/98553 A1 12/2001

(73) **Assignee:** Zond, Inc., Mansfield, MA (US)

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(*) **Notice:** Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 0 days.

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This patent is subject to a terminal disclaimer.

(21) **Appl. No.:** 10/249,844

(22) **Filed:** May 12, 2003

Related U.S. Application Data

(63) Continuation-in-part of application No. 10/249,595, filed on Apr. 22, 2003.

(51) **Int. Cl.⁷** H01J 7/24

(52) **U.S. Cl.** 315/111.21; 315/111.41; 156/345.44; 118/723 DC

(58) **Field of Search** 315/111.21, 111.41, 315/111.61, 111.71, 111.81, 111.91; 204/298.07, 298.08, 298.121, 298.161, 298.2, 298.21, 298.22; 156/345.33, 345.35, 345.38, 345.39, 345.4, 345.41, 345.42, 345.43, 345.44, 345.46; 118/723 ME, 723 DC, 723 I, 723 IR

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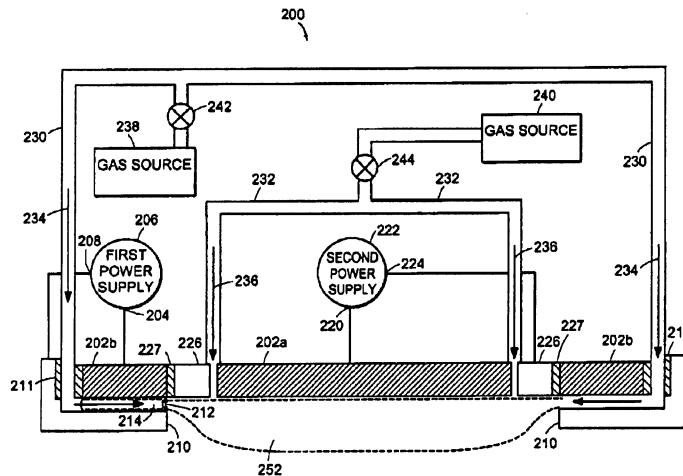
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(57) **ABSTRACT**

The plasma source includes a cathode assembly. An anode is positioned adjacent to the cathode assembly. An excited atom source generates an initial plasma and excited atoms from a volume of feed gas. The initial plasma and excited atoms are located proximate to the cathode assembly. A power supply generates an electric field between the cathode assembly and the anode. The electric field super-ionizes the initial plasma so as to generate a high-density plasma.

35 Claims, 19 Drawing Sheets



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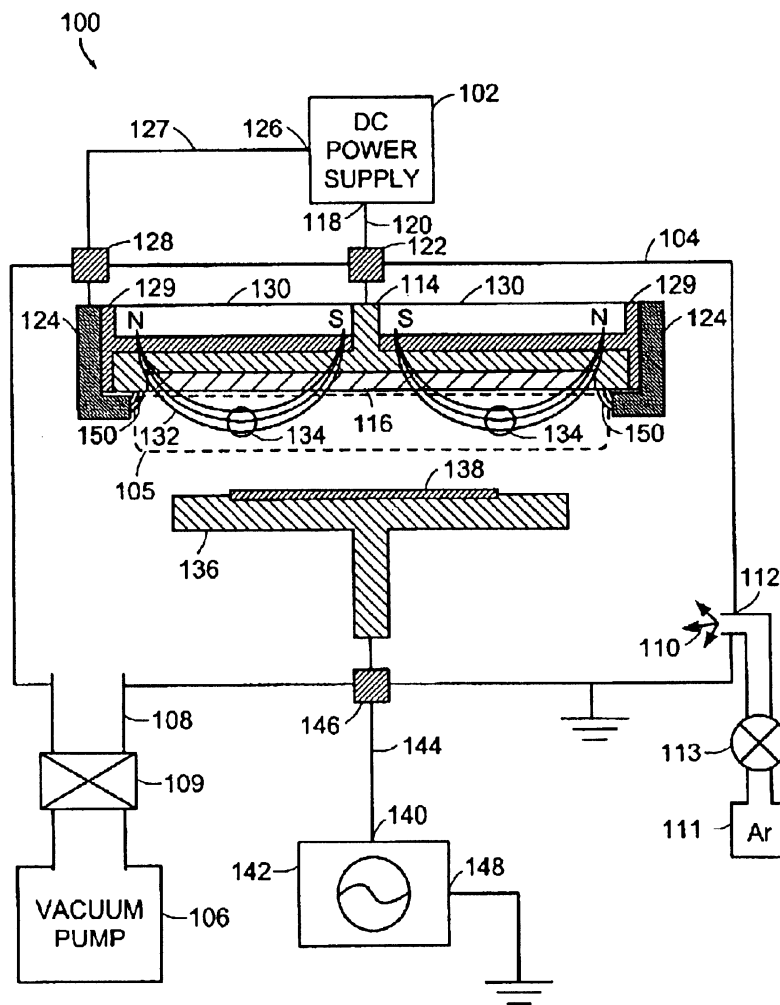


FIG. 1
PRIOR ART

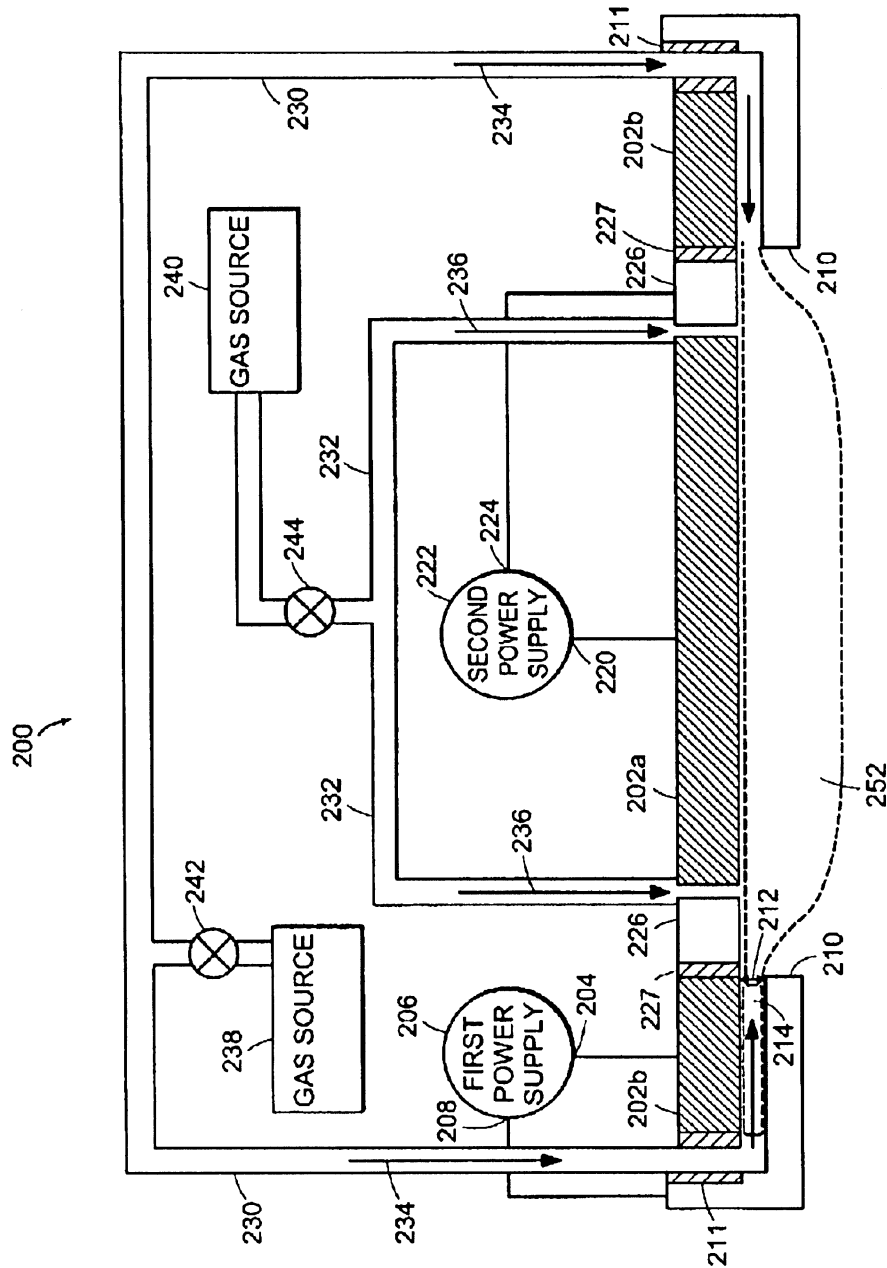


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